

NPN SILICON PLANAR MEDIUM POWER TRANSISTORS IN SOT89

Features

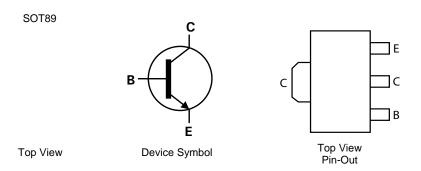
- I_c = 1A Continuous Collector Current
- Low Saturation Voltage V_{CE(sat)} < 500mV @ 0.5A
- Gain groups 10 and 16
- Epitaxial Planar Die Construction
- Complementary PNP types: BCX51, 52 and 53
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Devices (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: SOT89
- Case Material: Molded Plastic, "Green" Molding Compound (Note 2)
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.072 grams (Approximate)

Applications

- Medium Power Switching or Amplification Applications
- AF driver and output stages



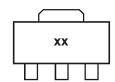
Ordering Information (Note 3 & 4)

Product	Grade	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCX54TA	Commercial	BA	7	12	1,000
BCX5410TA	Commercial	BC	7	12	1,000
BCX5416TA	Commercial	BD	7	12	1,000
BCX55TA	Commercial	BE	7	12	1,000
BCX5510TA	Commercial	BG	7	12	1,000
BCX5516TA	Commercial	BM	7	12	1,000
BCX56TA	Commercial	BH	7	12	1,000
BCX5610TA	Commercial	BK	7	12	1,000
BCX5616TA	Commercial	BL	7	12	1,000
BCX5616QTA	Automotive	BL	7	12	1,000
BCX5616TC	Commercial	BL	13	12	4,000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" Policy can be found on our website at http://www.diodes.com
- 3. For packaging details, go to our website http://www.diodes.com
- 4. Products with Q-suffix are automotive grade. Automotive products are electrical and thermal the same as the commercial, except where specified.

Marking Information



xx = Product Type Marking Code, as follows:

 BCX54
 = BA
 BCX55
 = BE
 BCX56
 = BH

 BCX5410
 = BC
 BCX5510
 = BG
 BCX5610
 = BK

 BCX5416
 = BD
 BCX5516
 = BM
 BCX5616
 = BL



Maximum Ratings @ T_A = 25℃ unless otherwise specified

Characteristic	Symbol	BCX54	BCX55	BCX56	Unit
Collector-Base Voltage	V _{CBO}	45	60	100	V
Collector-Emitter Voltage	V _{CEO}	45	60	80	V
Emitter-Base Voltage	V_{EBO}	5			V
Continuous Collector Current	Ic	1			А
Peak Pulse Collector Current	I _{CM}				
Continuous Base Current	I _B		100		
Peak Pulse Base Current	I _{BM}		mA mA		

Thermal Characteristics @ TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 4)	P _D	1	W
Thermal Resistance, Junction to Ambient (Note 4)	$R_{ heta JA}$	124	°C/W
Thermal Resistance, Junction to Leads (Note 5)	$R_{\theta JL}$	10.0	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-65 to +150	°C

Notes:

^{4.} For a device surface mounted on 25mm X 25mm FR4 PCB with high coverage of single sided 1 oz copper, in still air conditions; the device is measured when operating in a steady-state condition.

5. Thermal resistance from junction to solder-point (on the exposed collector pad).

25mm x 25mm 1oz Cu

T_{amb} = 25℃

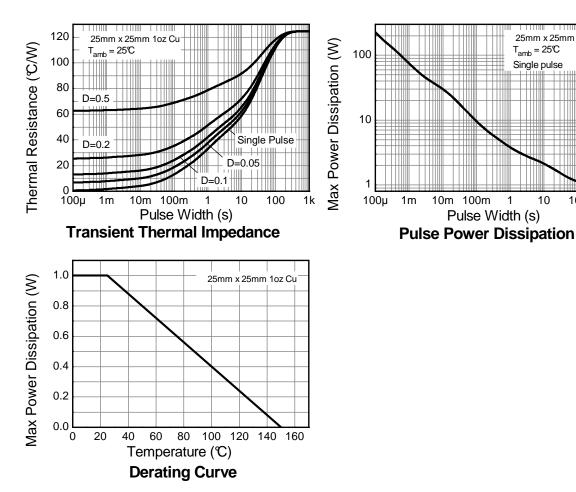
Single pulse

10m 100m

Pulse Width (s)



Thermal Characteristics

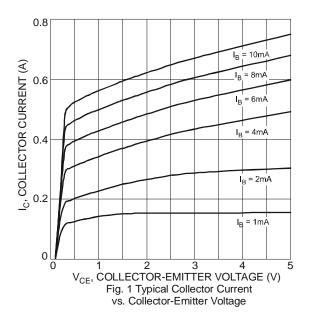


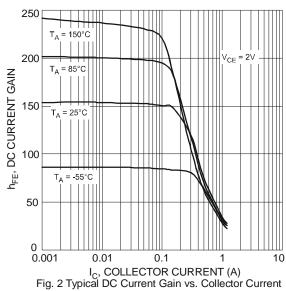


Electrical Characteristics @ T_A = 25°C unless otherwise specified

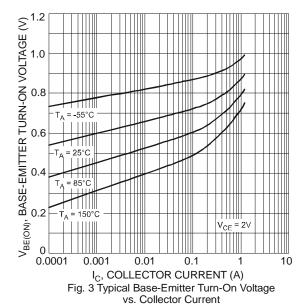
Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BCX54 BCX55 BCX56	BV _{CBO}	45 60 100	-	-	V	I _C = 100μA
Collector-Emitter Breakdown Voltage (Note 6)	BCX54 BCX55 BCX56	BV _{CEO}	45 60 80	-	ı	V	I _C = 10mA
Emitter-Base Breakdown Voltage		BV_{EBO}	5	-	-	V	$I_E = 10\mu A$
Collector Cut-off Current		Ісво	-	-	0.1 20	μA	V _{CB} = 30V V _{CB} = 30V, T _A = 150℃
Emitter Cut-off Current		I _{EBO}	-	-	20	nA	$V_{EB} = 4V$
Static Forward Current Transfer Ratio (Note 6)	All versions	h _{FE}	25 40 25	- - -	- 250 -		I _C = 5mA, V _{CE} = 2V I _C = 150mA, V _{CE} = 2V I _C = 500mA, V _{CE} = 2V
	10 gain grp 16 gain grp		63 100	-	160 250		$I_C = 150 \text{mA}, V_{CE} = 2V$ $I_C = 150 \text{mA}, V_{CE} = 2V$
Collector-Emitter Saturation Voltage (Note 6)		V _{CE(sat)}	-	-	0.5	V	I _C = 500mA, I _B = 50mA
Base-Emitter Turn-On Voltage (Note 6)		$V_{BE(on)}$	-	-	1.0	V	I _C = 500mA, V _{CE} = 2V
Transition Frequency		f⊤	150	-	-	MHz	I _C = 50mA, V _{CE} = 10V f = 100MHz
Output Capacitance		Cobo	-	-	25	pF	V _{CB} = 10V, f = 1MHz

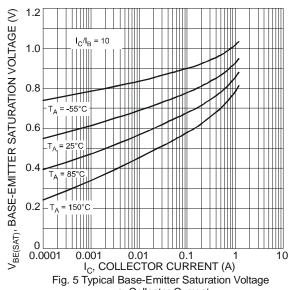
Notes: 6. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.

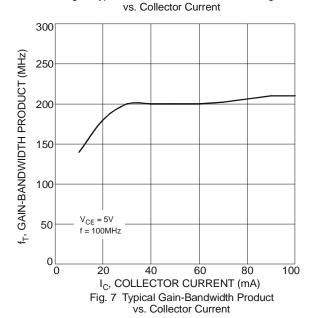












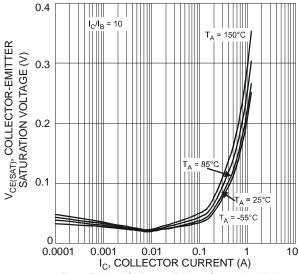


Fig. 4 Typical Collector-Emitter Saturation Voltage vs. Collector Current

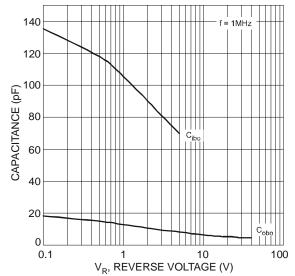
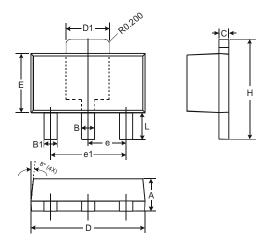


Fig. 6 Typical Capacitance Characteristics

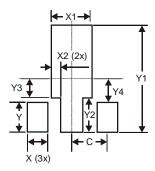


Package Outline Dimensions



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.43		
D	4.40	4.60		
D1	1.52	1.83		
Е	2.29	2.60		
Е	1.50 Typ			
e1	3.00 Typ			
Н	3.94	4.25		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout



Dimensions	Value (in mm)
Х	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500



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